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Phase evolution during mechanochemical synthesis of the PMN powders	SP-011-P
Zorica Brankovic Instituto de Quimica, UNESP, Araraquara, SP, Brazil	
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Low temperature synthesis of PMN-PT composite thick films for electromechanical applications	SP-015-P
Aiying Wu  Department of Ceramics and Glass Engineering, University of Aveiro, CICECO, Aveiro, Portugal	
Effect of boron oxide addition on sintering zirconia-yttria ceramics  Daniel Zanetti de Florio	SP-016-P
Energy and Nuclear Research Institute, Multidisciplinary Center for the Development of Ceramic Materials, S. Paulo, SP, Brazil	
Low temperature formation of SnO <sub>2</sub> thin films by a spray pyrolysis deposition method	SP-017-P
Shoji Kaneko Department of Materials Science and Technology, Shizuoka University, Johoku, Hamamatsu, Japan	
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Pyroelectric composites and ceramics based on LaBGeO <sub>5</sub> stillwellite <b>Pasquale Pernice</b> Department of Materials and Production Engineering, University of Naples Federico II,  Naples, Italy	SP-020-P
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Pradyot Datta	
Max-Planck-Institute for Metallforschung, PML, Stuttgart, Germany	CD 022 D
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Microstructure and optical transmittance of tungsten doped PLZT as a function of the hot pressing conditions  Ducinei Garcia	SP-026-P
Physics Department, Federal University of Sao Carlos, Sao Carlos, SP, Brasil  PST powder with sell gal process in type cesting and firing	SP-027-P
BST powder with sol-gel process in tape casting and firing <b>Tao Hu</b> Microelectronics and Material Physics Laboratories, Research Group of Infotech Oulu,	SF-U2/-F
University of Oulu, Linnanmaa, Oulu, Finland	

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Department of Ceramics and Glass Engineering, University of Aveiro, CICECO, Aveiro, Portugal	
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Institute for Energetics and Intephases, National Research Council, Genoa, Italy	

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Industrial Research Limited, Gracefield, Lower Hutt, New Zealand	
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Department of Materials Science and Engineering, National Tsing-Hua University, Hsin-Chu, Taiwan, R.O.C.	
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NYS Center for Advanced Ceramic Technology, Alfred University, NY, USA	CD 0/2 D
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Colin Leach	C11-009-1
Manchester Materials Science Centre, University of Manchester and UMIST, Manchester, United Kingdom	
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Research Center for Electronic Ceramics, Physics Department, DongEui University, Korea	
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Universidade Federal do Ceara, Fortaleza CE, Brazil	
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Departamento de Engenharia de Materiais, Universidade Federal de Sao Carlos, Sao Carlos, SP, Brazil	
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Scientific Research Company "Carat", Lviv Scientific Research Institute of Materials, Lviv, Ukraine	
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Department of Applied Physics, The Hong Kong Polytechnic, University Hunghom, Kowloon, Hong Kong, China	
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Multidisciplinary Center for the Development of Ceramic Materials-CCTM, Energy and Nuclear Research Institute, S. Paulo, SP, Brasil	
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Miroslaw M. Bucko  Faculty of Materials Science and Ceramics, University of Mining and Metallurgy, Cracow,  Poland	
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Instituto de Catalisis, CSIC Campus de Cantoblanco, Madrid, Spain	
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Laboratory for Industrial Energy Systems (LENI), Swiss Federal Institute of Technology (EPFL), Lausanne, Switzerland	

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Ceramics and Glass Eng. Dep., University of Aveiro, Aveiro, Portugal	
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Department of Ceramics and Glass Engineering, CICECO, University of Aveiro, Aveiro, Portugal	
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Italy	
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Max-Planck-Institute for Solid State Research, Stuttgart Germany	
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Dept. of Chemistry, Università di Modena, Modena, Italy	
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Research Institute of Technical Physics, Russian federal Nuclear Center - Ac. Zababakhin,	
Snezhinsk, Chelyabinsk region, Russia	
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Electroceramics Department, Instituto de Ceramica Y Vidrio, CSIC, Madrid, Spain	EC 015 D
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INFM e Dipartimento di Chimica e Chimica Industriale, Università di Genova, Genova, Italy	
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Institute of Materials Science, Thin Films Division, Darmstadt University of Technology,	
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Cathodic properties of LaMnO <sub>3</sub> electrode for fuel cells based on LaGaO <sub>3</sub> solid electrolyte	FC-017-P
Jae Yeon Yi	
Department of Materials Science and Engineering, Pohang University of Science and	
Technology, Pohang, South Korea	
Synthesis, characterization and electrical properties of CeO <sub>2</sub> -based anodes for SOFC	FC-018-P
Joseph Sfeir	
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Science Park, Lausanne, EPFL, Switzerland	
SE-Chemical Sensors	
Ceramics response to reducing gases: porosity influence	SE-008-P
Pedro Manuel Faia	SE-008-P
Pedro Manuel Faia Departamento de Engenharia Electrotecnica e Computadores- Faculdade de Ciencias e	SE-008-P
Pedro Manuel Faia Departamento de Engenharia Electrotecnica e Computadores- Faculdade de Ciencias e Tecnologia, Universidade de Coimbra, Coimbra, Portugal	
Pedro Manuel Faia  Departamento de Engenharia Electrotecnica e Computadores- Faculdade de Ciencias e Tecnologia, Universidade de Coimbra, Coimbra, Portugal  Binary Cr/W mixed oxide thin films prepared by physical methods for gas sensing applications	SE-008-P SE-010-P
Pedro Manuel Faia  Departamento de Engenharia Electrotecnica e Computadores- Faculdade de Ciencias e  Tecnologia, Universidade de Coimbra, Coimbra, Portugal  Binary Cr/W mixed oxide thin films prepared by physical methods for gas sensing applications  Carlo Cantalini	
Pedro Manuel Faia  Departamento de Engenharia Electrotecnica e Computadores- Faculdade de Ciencias e Tecnologia, Universidade de Coimbra, Coimbra, Portugal  Binary Cr/W mixed oxide thin films prepared by physical methods for gas sensing applications	
Pedro Manuel Faia  Departamento de Engenharia Electrotecnica e Computadores- Faculdade de Ciencias e  Tecnologia, Universidade de Coimbra, Coimbra, Portugal  Binary Cr/W mixed oxide thin films prepared by physical methods for gas sensing applications  Carlo Cantalini	
Pedro Manuel Faia  Departamento de Engenharia Electrotecnica e Computadores- Faculdade de Ciencias e Tecnologia, Universidade de Coimbra, Coimbra, Portugal  Binary Cr/W mixed oxide thin films prepared by physical methods for gas sensing applications Carlo Cantalini Dept. of Chemistry, University of L'Aquila, L'Aquila, Italy  Separation techniques for nanostructured chemoresistive sensors Matteo Ferroni	SE-010-P
Pedro Manuel Faia  Departamento de Engenharia Electrotecnica e Computadores- Faculdade de Ciencias e Tecnologia, Universidade de Coimbra, Coimbra, Portugal  Binary Cr/W mixed oxide thin films prepared by physical methods for gas sensing applications Carlo Cantalini Dept. of Chemistry, University of L'Aquila, L'Aquila, Italy  Separation techniques for nanostructured chemoresistive sensors	SE-010-P
Pedro Manuel Faia  Departamento de Engenharia Electrotecnica e Computadores- Faculdade de Ciencias e Tecnologia, Universidade de Coimbra, Coimbra, Portugal  Binary Cr/W mixed oxide thin films prepared by physical methods for gas sensing applications Carlo Cantalini Dept. of Chemistry, University of L'Aquila, L'Aquila, Italy  Separation techniques for nanostructured chemoresistive sensors Matteo Ferroni INFM and Physics Dept. of Ferrara University, Ferrara, Italy	SE-010-P
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Pedro Manuel Faia  Departamento de Engenharia Electrotecnica e Computadores- Faculdade de Ciencias e Tecnologia, Universidade de Coimbra, Coimbra, Portugal  Binary Cr/W mixed oxide thin films prepared by physical methods for gas sensing applications Carlo Cantalini Dept. of Chemistry, University of L'Aquila, L'Aquila, Italy  Separation techniques for nanostructured chemoresistive sensors  Matteo Ferroni INFM and Physics Dept. of Ferrara University, Ferrara, Italy  Electrical properties of non-ohmic SnO <sub>2</sub> -based ceramics in different relative humidity environnments  Alexander Glot Dep. of Radioelectronics, Dniepropetrovsk National University, Dniepropetrovsk, Ukraine  Degradation of oxide varistors ceramics in air atmosphere with NO <sub>2</sub> impurities at elevated temperature	SE-010-P SE-011-P SE-012-P
Pedro Manuel Faia  Departamento de Engenharia Electrotecnica e Computadores- Faculdade de Ciencias e Tecnologia, Universidade de Coimbra, Coimbra, Portugal  Binary Cr/W mixed oxide thin films prepared by physical methods for gas sensing applications Carlo Cantalini Dept. of Chemistry, University of L'Aquila, L'Aquila, Italy  Separation techniques for nanostructured chemoresistive sensors Matteo Ferroni INFM and Physics Dept. of Ferrara University, Ferrara, Italy  Electrical properties of non-ohmic SnO <sub>2</sub> -based ceramics in different relative humidity environnments Alexander Glot Dep. of Radioelectronics, Dniepropetrovsk National University, Dniepropetrovsk, Ukraine Degradation of oxide varistors ceramics in air atmosphere with NO <sub>2</sub> impurities at elevated temperature Alexander Glot	SE-010-P SE-011-P SE-012-P
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Pedro Manuel Faia  Departamento de Engenharia Electrotecnica e Computadores- Faculdade de Ciencias e Tecnologia, Universidade de Coimbra, Coimbra, Portugal  Binary Cr/W mixed oxide thin films prepared by physical methods for gas sensing applications Carlo Cantalini  Dept. of Chemistry, University of L'Aquila, L'Aquila, Italy  Separation techniques for nanostructured chemoresistive sensors  Matteo Ferroni  INFM and Physics Dept. of Ferrara University, Ferrara, Italy  Electrical properties of non-ohmic SnO <sub>2</sub> -based ceramics in different relative humidity environnments  Alexander Glot  Dep. of Radioelectronics, Dniepropetrovsk National University, Dniepropetrovsk, Ukraine  Degradation of oxide varistors ceramics in air atmosphere with NO <sub>2</sub> impurities at elevated temperature  Alexander Glot  Dep. of Radioelectronics, Dniepropetrovsk National University, Dniepropetrovsk, Ukraine  Solid-state amperometric CO <sub>2</sub> sensor using a sodium ion conductor  Ji-Sun Lee	SE-010-P SE-011-P SE-012-P SE-013-P
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Pedro Manuel Faia Departamento de Engenharia Electrotecnica e Computadores- Faculdade de Ciencias e Tecnologia, Universidade de Coimbra, Coimbra, Portugal Binary Cr/W mixed oxide thin films prepared by physical methods for gas sensing applications Carlo Cantalini Dept. of Chemistry, University of L'Aquila, L'Aquila, Italy Separation techniques for nanostructured chemoresistive sensors Matteo Ferroni INFM and Physics Dept. of Ferrara University, Ferrara, Italy Electrical properties of non-ohmic SnO2-based ceramics in different relative humidity environnments Alexander Glot Dep. of Radioelectronics, Dniepropetrovsk National University, Dniepropetrovsk, Ukraine Degradation of oxide varistors ceramics in air atmosphere with NO2 impurities at elevated temperature Alexander Glot Dep. of Radioelectronics, Dniepropetrovsk National University, Dniepropetrovsk, Ukraine Solid-state amperometric CO2 sensor using a sodium ion conductor Ji-Sun Lee School of Materials Science and Engineering, Seoul National University, Seoul, Korea Low temperature sol-gel synthesis and sensing properties of Cr2xTixO3 Giovanni Neri Dipartimento di Chimica Industriale e Ingegneria dei Materiali, Università di Messina, Messina, Italy Electrical modeling of the humidity sensing properties of doped Fe2O3 thin films Giovanni Neri	SE-010-P SE-011-P SE-012-P SE-013-P SE-015-P
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perionic phase transitions in the series of Li,Na <sub>1</sub> ,Ta,Nb <sub>1-2</sub> O <sub>3</sub> solid solutionceramics artists Bormanis stitute of Solid State Physics, University of Latvia, Riga, Latvia  perionic phase transitions in the series of Li,Na <sub>1</sub> ,Ta,Nb <sub>1-2</sub> O <sub>3</sub> solid solutionceramics artists Bormanis stitute of Solid State Physics, University of Latvia, Riga, Latvia  road-band dielectric response of doped incipient ferroelectrics lktor Bovtun  pearment of Dielectrics, Institute of Physics, Academy of Sciences of the Czech Republic, argue, Czech Republic  ass-ceramic materials with regulated dielectric properties based on the system BaO-PbO-O <sub>2</sub> -B <sub>2</sub> O <sub>2</sub> -Al <sub>2</sub> O <sub>3</sub> texander Gorokhovsky  mit of el investigacion y Estudios Avanzados, CINVESTAV Unidad Saltillo, Saltillo, Coahuila, exico  mpositional evolution of structural phase transitions in sodium niobate  silitu de Ciencia de Materiales de Madrid, CSIC, Madrid, Spain  ray study and dielectric properties of Sc-substituted Pb (Yb <sub>1/2</sub> Ta <sub>1/2</sub> )O <sub>3</sub> ceramics  i-i-i-i-yun Kim  requarment of Materials Science and Engineering, Korea Advanced Institute of Science and exhalogy, Taejon, Korea  requared to Materials Science and Engineering, Korea Advanced Institute of Science and exhalogy, Taejon, Korea  received Csl <sub>2</sub> Nb <sub>2</sub> O <sub>3</sub> prochlore based ferroelectric relaxors and glasses  N. Kolpakova  FE-013-P  recent Kim  pearment of Materials Science and Engineering, Korea Advanced Institute of Science and exhalogy, Taejon, Korea  received Csl <sub>2</sub> Nb <sub>2</sub> O <sub>3</sub> prochlore based ferroelectric relaxors and glasses  N. Kolpakova  FE-018-P  N. Kolpakova  FE-020-P  Teroelectric evensus relaxor behaviour in some bismuth layered oxide ceramics and sunters, Sao Carlos - S.P., Brazil  man Mitoseriu  pel of Electricity, Cuza University, Iasi, Romania  road-band dielectric response of SfTiO <sub>3</sub> Bi ceramics  ktor Porokhonskyy  stitut of Physics ASCR , Prague, Czech Republic	E- Ferroelectrics	
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	b(B',B")O <sub>3</sub> binary system as electrocaloric materials for room temperature refrigeration	FE-028-P
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stitute of Solis State Physics, University of Latvia, Riga, Latvia	nstitute of Solis State Physics, University of Latvia, Riga, Latvia	

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Department of Material Science, Faculty of Engineering Science, University of Silesia, Sosnowiec, Poland	
From incipient ferroelectricity in CaTiO <sub>3</sub> to real ferroelectricity in Ca <sub>1-x</sub> Pb <sub>x</sub> TiO <sub>3</sub> solid solutions <b>Andrei V. Sotnikov</b> <i>Institute of Solid State and Materials Research, Dresden, Germany</i>	FE-031-P
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E-T phase diagram of 6.5/65/35 PLZT ceramics <b>Boris Vodopivec</b>	FE-033-P
Josef Stefan Institute, Ljubljana, Slovenia	
The dielectric properties and phase transitions of (1-x)Pb (Yb <sub>1/2</sub> Ta <sub>1/2</sub> )O <sub>3</sub> - xPb (Fe <sub>1/2</sub> Ta <sub>1/2</sub> )O <sub>3</sub> Sang Chul Youn	FE-034-P
Department of Materials Science and Engineering, Korea Advanced Institute of Science and Technology, Taejon, Korea	
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Harvey Amorin	
Department of Ceramic & Glass Engeenering, University of Aveiro, CICECO, Aveiro, Portugal	
Effect of Ta <sub>2</sub> O <sub>5</sub> doping on the crystal structures and ferroelectromagnetic properties of PrFeO <sub>3</sub> -PbTiO <sub>3</sub> and BiFeO <sub>3</sub> -PbTiO <sub>3</sub> solid solution systems  Jeong Seog Kim	FE-036-P
Dept. of Materials Engineering, Hoseo University, Chungnam-do, Korea	
Coexistence of relaxor and ferroelectric phase in PLZT 6.5/65/35 ceramics  Cene Filipic  Institute Josef Stafan Jamesa, Liubliana, Slovenia	FE-037-P
Institute Josef Stefan Jamova, Ljubljana, Slovenia	
Dielectric and pyroelectric properties of the (Pb <sub>0.8</sub> Ba <sub>0.2</sub> ) [(Zn <sub>1/3</sub> Nb <sub>2/3</sub> ) <sub>0.7</sub> Ti <sub>0.3</sub> ]O <sub>3</sub> ferroelectric ceramic system with Ca and Sr impurities <b>Aime Pelaiz Barranco</b>	FE-038-P
Physics Faculty-Institute of Materials and Reagents, Havana University, La Habana, Cuba	
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Institute of Physics ASCR, Prague, Czech Republic	
PZ- Piezoelectrics	
The influence of the Zr <sup>4+</sup> / Ti <sup>4+</sup> ratio on the properties of lead zirconate titanate piezoelectric ceramics	PZ-009-P
Ana Maria Moisin	
R&D Institute for Electrical Engineering, Bucharest, Romania	
Piezoelectric PMN-PT ceramics from mechanochemically activated precursors  Miguel Alguero	PZ-010-P
Instituto de Ciencia de Materiales de Madrid, CSIC, Cantoblanco, Madrid, Spain	
Low temperature firing of PZT thick films prepared by screen printing method  Chae-il Cheon	PZ-011-P
Dept. of Materials Science & Eng., Hoseo University, Asan, Chungnam, Korea	
The structural phase diagram of PSN-PT system	PZ-013-P
Raphael Haumont  Laboratoire SPMS Structures, Proprits et Modelisation des Solides, Ecole Centrale Paris, Chitenay-Malabry, Paris, France	
Low-temperature fabrication of Pb(Ni <sub>1/3</sub> Nb <sub>2/3</sub> )O <sub>3</sub> - Pb(Zr <sub>0.3</sub> Ti <sub>0.7</sub> )O <sub>3</sub> ceramics with LiBiO <sub>2</sub> as a sintering aid <b>Takashi Hayashi</b>	PZ-014-P
Department of Materials Science, Shonan Institute of Technology, Fujisawa, Kanagawa, Japan	
Piezoelectric and optical properties of strontium doped PZT-NN ceramics	PZ-015-P
Elena Dimitriu National Institute for Materials Physics, Magurele, Jud.Ilfov, Romania	

Nonlinear piezoelectric coefficient of Pb(Ni, Nb)O <sub>3</sub> Pb (Zn, Nb)O <sub>3</sub> -PbZrO <sub>3</sub> -PbTiO <sub>3</sub> system ceramics	PZ-016-P
Keisuke Ishii	
Department of Materials Science and Engineering, The National Defense Academy, Yokosuka, Kanagawa, Japan	
Effect of simultaneous addition of BiFeO <sub>3</sub> and Ba(Cu <sub>0.5</sub> W <sub>0.5</sub> )O <sub>3</sub> on low temperature sintering of coprecipitated Pb(Zr,Ti)O <sub>3</sub> powders  Shoji Kaneko	PZ-019-P
Department of Materials Science and Technology, Shizuoka University, Hamamatsu, Japan	
Sodium-lithium niobate ceramics prepared by mechanochemical assisted methods  Lorena Pardo	PZ-020-P
Instituto de Ciencia de Materiales de Madrid., Madrid, Spain	
Fabrication of fluoridated PZT ceramics by solid state reaction  Benya Cherdhirunkorn	PZ-021-P
Manchester Materials Science Centre, University of Manchester and UMIST, Manchester, United Kingdom	
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Vitali Yu. Topolov Department of Physics, Rostov State University, Rostov-on-Don, Russia	
Electrical properties of alkali oxide piezoelectric materials  Masaaki Ichiki	PZ-025-P
Institute of Mechanical System Engineering, National Institute of Advanced Industrial Science and Technology, 1-2 Namiki, Tsukuba, Ibaraki, Japan	
Electrical properties of photovoltaic PLZT in application for energy transducers  Masaaki Ichiki	PZ-026-P
Institute of Mechanical System Engineering, National Institute of Advanced Industrial Science and Technology, Ibaraki, Japan	
DI- Dielectrics	
Structural and dielectric characterization of a new pyrochlore type family of materials: tin and lead tin niobates	DI-007-O
Luisa Paula Valente Cruz	
Dep. Environment, Polytechnic Institute of Viseu, Viseu, Portugal  Dielectric properties of BaFe <sub>x</sub> Ti <sub>(1-x)</sub> O <sub>3</sub>	DI-009-P
Salah Eddine Barama Ceramics Laboratory, Mentouri University, Constantine, Algeria	DI-009-I
Dielectric properties of BaTiO <sub>3</sub> -NaNbO <sub>3</sub> composites	DI-010-P
Med. Tahar Benlahrache Ceramics Laboratory, Mentouri University, Algeria	
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<b>Jerome Bernard</b> Laboratoire Universitaire des Sciences Appliques de Cherbourg (LUSAC EA2607), Site	
Jerome Bernard  Laboratoire Universitaire des Sciences Appliques de Cherbourg (LUSAC EA2607), Site  Universitaire, Cherbourge Octeville, France  BaTiO <sub>3</sub> with a lithium salt sintered at low temperatures in a reducing atmosphere	DI-012-P
Jerome Bernard  Laboratoire Universitaire des Sciences Appliques de Cherbourg (LUSAC EA2607), Site Universitaire, Cherbourge Octeville, France  BaTiO <sub>3</sub> with a lithium salt sintered at low temperatures in a reducing atmosphere  Jerome Bernard  Laboratoire Universitaire des Sciences Appliques de Cherbourg (LUSAC EA2607), Site Universitaire, Cherbourge Octeville, France	DI-012-P
Jerome Bernard  Laboratoire Universitaire des Sciences Appliques de Cherbourg (LUSAC EA2607), Site  Universitaire, Cherbourge Octeville, France  BaTiO <sub>3</sub> with a lithium salt sintered at low temperatures in a reducing atmosphere  Jerome Bernard  Laboratoire Universitaire des Sciences Appliques de Cherbourg (LUSAC EA2607), Site	DI-012-P DI-013-P

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Jae-Hwan Park Div. of Materials, Korea Institute of Science and Technology, Seoul, South Korea	
Cyclic unipolar electric fatigue of bulk PZT	DI-017-P
Cyril Verdier	D1-017-1
Institute of Materials Science, Darmstadt, Germany	
The role of C-impurities in alumina dielectrics	DI-018-P
Rafael Vila	
CIEMAT, Madrid, Spain	
Ultra-fine Ba <sub>2</sub> Ti <sub>9</sub> O <sub>20</sub> microwave dielectric materials synthesized by inverse microwave process	DI-022-P
Li-Wen Chu	
Department of Chemical Engineering, National Tsing-Hua University, Hsinchu, Taiwan	
TF- Ferroelectric Thin Films	
Anomalously high electromechanical response of a (Pb, La) TiO <sub>3</sub> thin film on a circular thin	TF-009-P
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Miguel Alguero Instituto de Ciencia de Materiales de Madrid, CSIC, Cantoblanco, Madrid, Spain	
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Iulian Boerasu	
Physics Center, University of Minho, Braga, Portugal	FF 012 P
Strontium titanate films prepared by spray pyrolysis  Goran Brankovic	TF-012-P
Instituto de Quimica, UNESP, Araraquara, SP, Brazil	
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Jose Antonio Eiras	
Grupo de Ceramicas Ferroeletricas, Departamento de Fisica, Universidade Federal de Sao Carlos, Sao Carlos, SP, Brazil	
Ferroelectric properties of nano-sized Pb(Zr, Ti)O <sub>3</sub> islands	TF-015-P
Hironori Fujisawa	
Department of Electronics, Faculty of Engineering, Himeji Institute of Technology, Himeji,	
Hyogo, Japan Stoichiometry and crystal orientation of YAG-PLD derived ferroelectric PZT thin film	TF-016-P
Ken-ichi Kakimoto	11-010-1
Department of Materials Science and Engineering, Inorganic Materials Division, Nagoya	
Institute of Technology, Nagoya, Japan	
Low temperature recrystallization of non stoichiometric SrBi <sub>3</sub> Nb <sub>2</sub> O <sub>9</sub> thin films and its effects on	TF-017-P
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Semiconductor Materials Laboratory, Korea Institute of Science and Technology, Seoul, Korea	
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Johannes Roedel	
Institute of Materials Science, Dresden University of Technology, Dresden, Germany	
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Bong Jin Kuh  Department of Materials Science and Engineering, Korea Advanced Institute of Science and	
Department of Materials Science and Engineering, Korea Advanced Institute of Science and Technology, Yusong-Gu, Taejon, Korea	
Residual stress in lead titanate thin film on different substrates	TF-021-P
Tomoya Ohno	
Faculty of Engineering, Shizuoka University, Hamamatsu, Shizuoka, Japan	
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Influence of oxygen atmosphere on crystallization and properties of lithium niobate thin films	11-022-1
Influence of oxygen atmosphere on crystallization and properties of lithium niobate thin films  Alexandre Simoes  Department of Chemistry-Physics, Chemistry Institute, UNESP, Araraquara-SP, Brazil	11-022-1

Compositional and structural study of ferroelectric multilayer (Pb, La)TiO <sub>3</sub> /(Pb, Ca)Ti <sub>3</sub> sol-gel	TF-023-P
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Rosalia Poyato	
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A statistical analysis of macroscopic and local responses in degraded hysteresis loops of PZT	TF-025-P
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Dan Ricinschi	
Graduate School of Engineering Science, Osaka University, Toyonaka, Osaka, Japan	
Ferroelectric properties of PbZr <sub>x</sub> Ti <sub>1-x</sub> O <sub>3</sub> thin films by low-temperature MOCVD	TF-027-P
Masaru Shimizu	
Department of Electronics, Faculty of Engineering, Himeji Institute of Technology, Hyogo,	
Japan	
Antiferroelectric PbZrO <sub>3</sub> thin films: structure, properties and irradiation effects	TF-028-P
Andrisb Sternberg	
Institute of Solid State Physics, University of Latvia, Riga, Latvia	
The influence of cation substitution on the crystallization of SrBi <sub>2</sub> Ta <sub>2</sub> O <sub>9</sub> thin films	TF-029-P
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Department of Materials Science & Engineering, Functional Nanostructured Materials	
Laboratory, Daejin University Pochun-koon, Kyunggi-do, South Korea	
Recostructive phase transitions of the pyrochlore- perovskite-type in PZT-based thin films	TF-030-P
Zygmunt Surowiak	
Faculty of Physics, Rostov State University, Rostov-on-Don, Russia	
Effects of Bi <sub>2</sub> O <sub>3</sub> seeding layer on crystallinity and electrical properties of sol-gel derived	TF-031-P
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Daichi Togawa	
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Zhan Jie Wang	
Department of Materials Processing, Graduate School of Engineering, Tohoku University,	
Sendai, Japan	
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Takayuki Watanabe	
Tokyo Institute of Technology, Yokohama-shi, Kanagawa, Japan	
Aqueous solution-gel synthesis of SrRuO <sub>3</sub>	TF-036-P
J. Pagnaer	
Laboratory of Inorganic and Physical Chemistry, Limburgs Universitair Centrum, IMO,	
Diepenbeek, Belgium	FF 027 P
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Dept. of Advanced Materials Engineering, Dong-Eui University, Busan, South Korea  Peridual stresses in Pt bettern electrodes for sol golderived lead given peter titenets thin films	TE 020 D
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National Institute of Advanced Industrial Science and Technology, Tsukuba, Ibaraki, Japan	
MW- Microwave Dielectrics and Applications	
Dielectric relaxation of SrBi <sub>2</sub> (Nb <sub>0.75</sub> Ta <sub>0.25</sub> ) <sub>2</sub> O <sub>9</sub> ceramics from 1 kHz to 1GHz	MW-010-P
Junzheng Liu	
Department of Applied Physics and Materials Research Center, The Hong Kong Polytechnic	
University, Hong Kong, China	
Relationship between Sr substitution for Ba and dielectric characteristics in Sm <sub>2</sub> BaZnO <sub>5</sub>	MW-011-P
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Kenkichi Mori Faculty of Science and Technology, Meijo University, Nagoya, Japan	

Microwave dielectric properties-structure relationship in Y <sub>2</sub> Ba(Cu <sub>1-x</sub> M <sub>x</sub> )O <sub>5</sub> (M=Co and Mg)	MW-012-P
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<b>Katsuhiro Mori</b> Faculty of Science and Technology, Meijo University, Nagoya, Japan	
Low-temperature sintering of Ba <sub>6-3x</sub> Sm <sub>8+2x</sub> Ti <sub>18</sub> O <sub>54</sub> microwave dielectric ceramics by B <sub>2</sub> O <sub>3</sub> and	MW-013-P
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Yutaka Ota	
Department of Materials Science and Engineering, Nagoya Institute of Technology, Nagoya,	
Japan	
Local cationic ordering behaviour in Ba(Mg <sub>1/3</sub> Nb <sub>2/3</sub> )O <sub>3</sub> ceramics	MW-014-P
Jae-Gwan Park	
Division of Materials, Korea Institute of Science and Technology, Seoul, Korea	
Microwave dielectric properties of low temperature sintering Ca[(Li <sub>1/3</sub> M <sub>2/3</sub> ),Ti]O <sub>3-y</sub> (M=Nb,Ta)	MW-015-P
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Liu Peng	
Faculty of Science and technology, Meijo University, Nagoya, Japan	
Vibrational spectroscopy study of the lattice defects in CaZrO <sub>3</sub> ceramics	MW-016-P
Michael Pollet	
Laboratoire CRISMAT, Caen, France	
Far-infrared reflection and microwave properties of Ba ([Mg <sub>1-x</sub> Zn <sub>x</sub> ] <sub>1/3</sub> Ta <sub>2/3</sub> )O <sub>3</sub> ceramics	MW-017-P
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R&D Center, Sumitomo Special Metals Co., Shimamoto-cho, Mishima-gun, Japan	
Processing and properties of BST and BZT thin films for tunable dielectric devices	MW-019-P
Jin Xu	14144 015 1
Institut für Werkstoffe der Electrotechnik, Universitaet Karlsruhe (TH), Karlsruhe, Germany	
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Influence of Zn and Ni substitution of Mg on dielectric properties of (Mg <sub>4-x</sub> M <sub>x</sub> )Nb <sub>2</sub> O <sub>9</sub> (M=Zn and Ni) solid solutions	M W -020-P
Atsushi Yoshida	
Faculty of Science and Technology, Meijo University, Nagoya, Japan	
Investigation of Ag(Ta,Nb)O <sub>3</sub> as tunable microwave dielectric	MW-021-P
Frederic Zimmermann	
Institut für Werkstoffe der Elektrotechnik (IWE), Universitaet Karlsruhe, Karlsruhe, Germany	
Low temperature co-friable ceramics glass-ceramic composites for microwave device	MW-022-P
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Cheng-Sao Chen	
Department of Mechanical Engineering, National Taiwan University of Science and	
Technology, Taipei, Taiwan	
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Chung-Chin Cheng	
Department of Materials Science and Engineering, National Chiao-Tung University, Hsinchu,	
Taiwan	
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$BI_2(ZN_{1/3}Nb_{2/3})_2O_7$ thin films	
Hsiu-Fung Cheng  Department of Physics National Taiwan Normal University Tainai Taiwan	
Department of Physics, National Taiwan Normal University, Taipei, Taiwan	
ED- Electroceramic Devices	
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Harry Tuller	
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Grains size effects on electric and piezoelectric constants of PZT ceramic transducers	ED-009-P
Mohammed Kadri	
Department of Electronic, Faculty of Electrical Engineering, University of Sciences and	
Technology of Oran, Oran, Algeria	

Modeling of polycrystal piezoceramic transducers	ED-010-P
Mohammed Kadri Department of Electronic, Faculty of Electrical Engineering, University of Sciences and	
Technology of Oran, Oran, Algeria	
High-power characteristics of piezoceramic resonators	ED-012-P
Eberhard Hennig PI Ceramic GmbH Lindenstrasse, Lederhose, Germany	
Effect of the laser processing in RAINBOW actuators	ED-013-P
Jari Juuti	LD 013 1
Microelectronics and Material Physics Laboratories, Research Group of Infotech Oulu, University of Oulu, Oulu, Finland	
Synthesis of functional ceramic coatings on the surface of glassy substrates by treatment with molten salt mixtures	ED-014-P
Alexander Gorokhovsky	
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Piezoresistive anisotropy of thick-film resistors	ED-015-P
Claudio Grimaldi Laboratoire de Production Microtechnique, Ecole Polytechnique Federale de Lausanne, Lausanne, Switzerland	
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<b>Thomas Maeder</b> Laboratoire de Production Microtechnique, Ecole Polytechnique Federale de Lausanne,	
Lausanne, Switzerland	
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Departament of Materials Science, Faculty of Engineering, University of Silesia, Sosnowiec, Poland	
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concentrations  Fabio C. Fonseca  Instituto de Fisica, Universidade de S. Paulo, S. Paulo, SP, Brazil  The origin of room temperature ferromagnetism in the Co- doped ZnO thin films fabricated by pulsed laser deposition  Jae Hyun Kim	
concentrations  Fabio C. Fonseca  Instituto de Fisica, Universidade de S. Paulo, S. Paulo, SP, Brazil  The origin of room temperature ferromagnetism in the Co- doped ZnO thin films fabricated by pulsed laser deposition  Jae Hyun Kim  Department of Materials Science and Engineering, Korea Advanced Institute of Science and	
concentrations  Fabio C. Fonseca  Instituto de Fisica, Universidade de S. Paulo, S. Paulo, SP, Brazil  The origin of room temperature ferromagnetism in the Co- doped ZnO thin films fabricated by pulsed laser deposition  Jae Hyun Kim	
concentrations  Fabio C. Fonseca  Instituto de Fisica, Universidade de S. Paulo, S. Paulo, SP, Brazil  The origin of room temperature ferromagnetism in the Co- doped ZnO thin films fabricated by pulsed laser deposition  Jae Hyun Kim  Department of Materials Science and Engineering, Korea Advanced Institute of Science and Technology, Taejon, Korea  Production by solid/liquid reaction and characterisation of high purity MgB2 for superconducting application	SM-007-P
concentrations  Fabio C. Fonseca  Instituto de Fisica, Universidade de S. Paulo, S. Paulo, SP, Brazil  The origin of room temperature ferromagnetism in the Co- doped ZnO thin films fabricated by pulsed laser deposition  Jae Hyun Kim  Department of Materials Science and Engineering, Korea Advanced Institute of Science and Technology, Taejon, Korea  Production by solid/liquid reaction and characterisation of high purity MgB2 for superconducting application  Silvia Bodoardo	SM-007-P
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concentrations  Fabio C. Fonseca  Instituto de Fisica, Universidade de S. Paulo, S. Paulo, SP, Brazil  The origin of room temperature ferromagnetism in the Co- doped ZnO thin films fabricated by pulsed laser deposition  Jae Hyun Kim  Department of Materials Science and Engineering, Korea Advanced Institute of Science and Technology, Taejon, Korea  Production by solid/liquid reaction and characterisation of high purity MgB2 for superconducting application  Silvia Bodoardo  Department of Material Science and Chemical Engineering, Politecnico di Torino, Torino, Italy  High-Tc phase obtained in the Pb/Sb doped Bi-Sr-Ca-Cu-O system  Victor Fruth  Institute of Physical Chemistry, Romanian Academy, Bucharest, Romania	SM-007-P SM-009-P SM-012-P
concentrations  Fabio C. Fonseca  Instituto de Fisica, Universidade de S. Paulo, S. Paulo, SP, Brazil  The origin of room temperature ferromagnetism in the Co- doped ZnO thin films fabricated by pulsed laser deposition  Jae Hyun Kim  Department of Materials Science and Engineering, Korea Advanced Institute of Science and Technology, Taejon, Korea  Production by solid/liquid reaction and characterisation of high purity MgB2 for superconducting application  Silvia Bodoardo  Department of Material Science and Chemical Engineering, Politecnico di Torino, Torino, Italy  High-Tc phase obtained in the Pb/Sb doped Bi-Sr-Ca-Cu-O system  Victor Fruth  Institute of Physical Chemistry, Romanian Academy, Bucharest, Romania  Growth and characterisation of lead hexaferrite films by pulsed laser deposition	SM-007-P SM-009-P
concentrations  Fabio C. Fonseca  Instituto de Fisica, Universidade de S. Paulo, S. Paulo, SP, Brazil  The origin of room temperature ferromagnetism in the Co- doped ZnO thin films fabricated by pulsed laser deposition  Jae Hyun Kim  Department of Materials Science and Engineering, Korea Advanced Institute of Science and Technology, Taejon, Korea  Production by solid/liquid reaction and characterisation of high purity MgB2 for superconducting application  Silvia Bodoardo  Department of Material Science and Chemical Engineering, Politecnico di Torino, Torino, Italy  High-Tc phase obtained in the Pb/Sb doped Bi-Sr-Ca-Cu-O system  Victor Fruth  Institute of Physical Chemistry, Romanian Academy, Bucharest, Romania  Growth and characterisation of lead hexaferrite films by pulsed laser deposition  Bernard Watts	SM-007-P SM-009-P SM-012-P
concentrations Fabio C. Fonseca Instituto de Fisica, Universidade de S. Paulo, S. Paulo, SP, Brazil The origin of room temperature ferromagnetism in the Co- doped ZnO thin films fabricated by pulsed laser deposition Jae Hyun Kim Department of Materials Science and Engineering, Korea Advanced Institute of Science and Technology, Taejon, Korea Production by solid/liquid reaction and characterisation of high purity MgB2 for superconducting application Silvia Bodoardo Department of Material Science and Chemical Engineering, Politecnico di Torino, Torino, Italy High-Tc phase obtained in the Pb/Sb doped Bi-Sr-Ca-Cu-O system Victor Fruth Institute of Physical Chemistry, Romanian Academy, Bucharest, Romania Growth and characterisation of lead hexaferrite films by pulsed laser deposition Bernard Watts Istituto IMEM/CNR, Parma, Italy	SM-007-P SM-009-P SM-012-P
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